

QUICKSWITCH[®] PRODUCTS HIGH-SPEED CMOS QUICKSWITCH 32-BIT MULTIWIDTH™ BUS SWITCHES

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FEATURES/BENEFITS

- Enhanced N channel FET with no inherent diode to Vcc
- Bidirectional switches connect inputs to outputs
- Zero propagation delay, zero ground bounce
- QS34X245 is 32-bit version of QS3245
- Flow-through pinout for easy layout
- Undershoot clamp diodes on all switch and control inputs
- TTL-compatible control inputs
- Available in MilliPaQ[™] Package

APPLICATIONS

- Hot-docking, hot-swapping applications
- Voltage translation (5V to 3.3V)
- Bus switching and isolation
- Power conservation
- Logic replacement (data processing)
- Capacitance isolation
- Clock gating

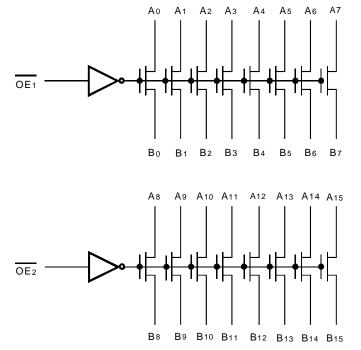
FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION

The QS34X245 is a member of the MultiWidthTM family of QuickSwitch devices and provides a set of 32 high-speed CMOS compatible bus switches in a flow-through pinout. This device is available in the MilliPaQ package, the world's first small outline 32-bit solution. The low ON-resistance of the QS34X245 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce noise. When Output Enable (\overline{OEn}) is low, the switches are turned on, connecting bus A to bus B. When \overline{OEn} is high, the switches are turned off. This device is ideally suited for 32/64 bit applications where board space is at a premium.

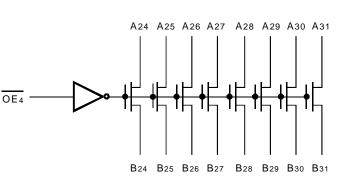
QuickSwitch devices provide speeds an order of magnitude faster than conventional logic devices.

The QS34X245 is characterized for operation at -40°C to +85°C.



A16 A17 A18 A19 A20 A21 A22 A23 OE3 Image: Align and align an

B16



B17 B18 B19

INDUSTRIAL TEMPERATURE RANGE

APRIL 2000

B20 B21 B22 B23

PIN CONFIGURATION

	1				-
NC		1	Ŭ	80	Vcc
A0		2		79	OE1
A1		3		78	B0
A2		4		77	B1
Aз		5		76	B2
A4		6		75	В3
A5	Π	7		74	B4
A6		8		73	B5
A7		9		72	B6
GND	Ц	10		71	B7
NC		11		70	Vcc
A8	Π	12		69	OE2
A9	Π	13		68	B8
A10		14		67	B9
A11		15		66	B10
A12		16		65	B11
A13		17		64	B12
A14	Γ	18		63	B13
A15	Γ	19		62	B14
GND	Γ	20		61	B15
NC		21		60	Vcc
A16		22		59	OE3
A17		23		58	B16
A18		24		57	B17
A19		25		56	B18
A20		26		55	B19
A21		27		54	B20
A22		28		53	B21
A23		29		52	B22
GND		30		51	B23
NC		31		50	Vcc
A24		32		49	OE4
A25		33		48	B24
A26		34		47	B25
A27		35		46	B26
A28		36		45	B27
A29		37		44	B28
A30		38		43	B29
A31		39		42	B30
GND		40		41	B31
	l	L			_1

MILLIPAQ TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	– 0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage Vs	– 0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage VIN	– 0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤20ns)	- 3	V
Ιουτ	DC Output Current	120	mA
Рмах	Maximum Power Dissipation (TA = 70°C)	1.4	W
Tstg	Storage Temperature	- 65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc Terminals.
- 3. All terminals except Vcc.

CAPACITANCE ⁽¹⁾

$(T_A = +25^{\circ}C, f = 1.0MHz, V_{IN} = 0V, V_{OUT} = 0V)$

Pins	Тур.	Max.	Unit
Control Inputs	3	4	pF
Quickswitch Channels (Switch OFF)	7	8	pF

NOTE:

1. Capacitance is characterized but not tested.

FUNCTION TABLE ⁽¹⁾

OEn	Function
Н	Disconnected
L	An = Bn

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

PIN DESCRIPTION

Pin Names	Description
OEn	Output Enable
An	Data I/Os
Bn	Data I/Os

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

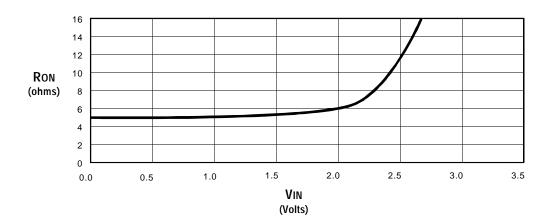
Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40°C to +85°C, Vcc = $5.0V \pm 5\%$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	2	_	-	V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Inputs	—	_	0.8	V
lin	Input Leakage Current (Control Inputs)	$V \le VIN \le Vcc$	—	_	±1	μA
loz	Off-State Current (Hi-Z)	$0V \le VOUT \le Vcc$, Switches Off	_	_	±1	μA
Ron	Switch ON Resistance	$Vcc = Min., V_{IN} = 0V, I_{ON} = 30mA$	—	5	7	Ω
		Vcc = Min., VIN = 2.4V, ION = 15mA	_	10	15	Ω
Vp	Pass Voltage ⁽²⁾	$V_{IN} = V_{CC} = 5V$, $I_{OUT} = -5\mu A$	3.7	4	4.2	V

NOTES:

- 1. Typical values are at Vcc = 5.0V, TA = 25° C.
- 2. Pass Voltage is guaranteed but not tested.

TYPICAL ON RESISTANCE vs Vin AT Vcc = 5.0V



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
lcco	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0	12	μA
ΔΙCC	Power Supply Current per Control Input HIGH ⁽²⁾	Vcc = Max., VIN = 3.4V , f = 0	1.5	mA
ICCD	Dynamic Power Supply Current per MHz ⁽³⁾	Vcc = Max., A and B pins open	0.25	mA/MHz
		Control Input Toggling at 50% Duty Cycle		

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per TLL driven input (VIN = 3.4V, control inputs only). A and B pins do not contribute to Δ Icc.

3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

$TA = -40^{\circ}C \text{ to } +85^{\circ}C, Vcc = 5.0V \pm 5\%$

 $C_{LOAD} = 50 pF$, $R_{LOAD} = 500 \Omega$ unless otherwise noted.

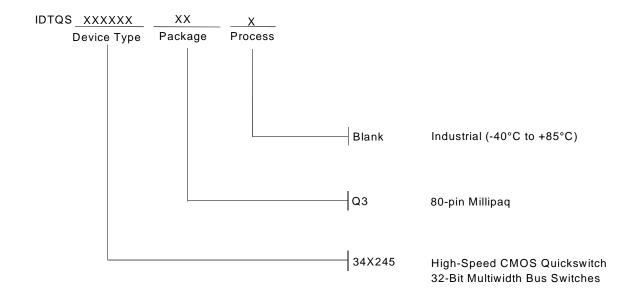
Symbol	Parameter	Min. ⁽¹⁾	Тур.	Max.	Unit
t PLH	Data Propagation Delay ^(1,2)			0.25	
t PHL	An to Bn, Bn to An	—	—	0.25	ns
tрzн	Switch Turn-On Delay	0.5		F 4	
tPZL	OE to An, Bn	0.5	-	5.6	ns
tphz	Switch Turn-Off Delay ⁽¹⁾	0.5		ΕĴ	
tPLZ	OE to An, Bn	0.5		5.2	ns

NOTES:

1. This parameter is guaranteed but not tested

2. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION





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